NSN 5961-01-159-7157

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-159-7157
Inclosure Material:
Metal
Overall Length:
0.185 inches
Terminal Length:
1.320 inches
Overall Diameter:
0.430 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 peak gate voltage
Current Rating Per Characteristic:
2.00 amperes source cutoff current outside diameter
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpnp
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0